Correction to Elevated Temperature Anodized Nb₂O₅—A Photoanode Material with Exceptionally Large Photoconversion

Efficiencies [ACS Nano 2012, 6, 4045–4053. DOI: 10.1021/nn300408p]. Jian Zhen Ou,* Rozina A Rani, Moon-Ho Ham, Matthew R Field, Yuan Zhang, Haidong Zheng, Peter Reece, Serge Zhuiykov, Sharath Sriram, Madhu Bhaskaran, Richard B Kaner, and Kourosh Kalantar-zadeh*

In the "E vs NHE (V)" axis (right side) of Figure 1, the values appeared inverse of what they should be. This does not influence any conclusions drawn from the article. The corrected figure appears below.

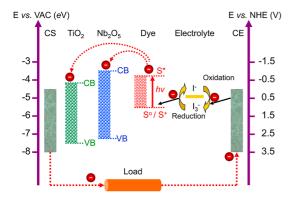


Figure 1. Energy states diagram of Nb₂O₅ and TiO₂ based DSSCs featuring their operation principle, in which CS, CE, CB, VB VAC, and NHE stand for "conductive substrate", "counter electrode", "conduction band", "valence band", "vacuum", and "normal hydrogen electrode", respectively.

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